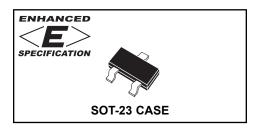
CMPD7000E

ENHANCED SPECIFICATION

SURFACE MOUNT
DUAL, SILICON SWITCHING DIODE
SERIES CONNECTION





DESCRIPTION:

The Central Semiconductor CMPD7000E is an Enhanced version of the CMPD7000 Dual, Series Configuration, Ultra-High Speed Switching Diode. This device is manufactured by the epitaxial planar process, in an epoxy molded surface mount SOT-23 package, designed for high speed switching applications.

MARKING CODE: C5CE

FEATURED ENHANCED SPECIFICATIONS:

- ♦ BV_R from 100V min to 120V min.
- ♦ V_F from 1.1V max to 1.0V max.

MAXIMUM RATINGS $(T_{\Delta}=25^{\circ}\text{C})$						
, A ,	SYMBOL		UNITS			
Peak Repetitive Reverse Voltage	V_{RRM}	120	V			
Average Forward Current	IO	200	mA			
Peak Forward Current	I _{FM}	500	mA			
Power Dissipation	P_{D}	350	mW			
Operating and Storage						
Junction Temperature	T_{J}, T_{stg}	-65 to +150	°C			
Thermal Resistance	Θ_{JA}^{-}	357	°C/W			
	Peak Repetitive Reverse Voltage Average Forward Current Peak Forward Current Power Dissipation Operating and Storage Junction Temperature	Peak Repetitive Reverse Voltage Average Forward Current Peak Forward Current Power Dissipation Operating and Storage Junction Temperature SYMBOL VRRM IO IFM PD TJ,Tstg	Peak Repetitive Reverse Voltage Average Forward Current Peak Forward Current IO 200 Peak Forward Current IFM 500 Power Dissipation PD 350 Operating and Storage Junction Temperature TJ,Tstg -65 to +150			

ELECTRICAL CHARACTERISTICS PER DIODE: (T_A=25°C unless otherwise noted)

	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
♦	BV_R	I _R =100μA	120	150		V
	I_{R}	V _R =50V			300	nA
	I_{R}	V _R =50V, T _A =125°C			100	μΑ
	I_{R}	V _R =100V			500	nA
♦	٧ _F	I _F =1.0mA	0.55	0.59	0.65	V
♦	V_{F}	I _F =10mA	0.67	0.72	0.77	V
♦	٧ _F	I _F =100mA	0.85	0.91	1.0	V
	C_T	V _R =0, f=1 MHz			1.5	pF
	t _{rr}	$I_R=I_F=10$ mA, $R_L=100\Omega$, Rec. to 1.0mA		2.0	4.0	ns

♦ Enhanced Specification

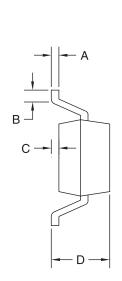


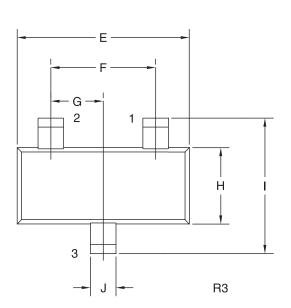
CMPD7000E

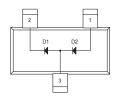
ENHANCED SPECIFICATION

SURFACE MOUNT **DUAL, SILICON SWITCHING DIODE SERIES CONNECTION**

SOT-23 CASE - MECHANICAL OUTLINE







LEAD CODE:

- 1) Anode D2
- 2) Cathode D1 3) Anode D1, Cathode D2

MARKING CODE: C5CE

DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
Α	0.003	0.007	0.08	0.18			
В	0.006	-	0.15				
С	ı	0.005	-	0.13			
D	0.035	0.043	0.89	1.09			
Е	0.110	0.120	2.80	3.05			
F	0.075		1.90				
G	0.037		0.95				
Н	0.047	0.055	1.19	1.40			
	0.083	0.098	2.10	2.49			
J	0.014	0.020	0.35	0.50			

SOT-23 (REV: R3)